Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-170-1954

| Inclosure I | Material: |
|--------------|---|
| Metal | |
| Overall Le | ngth: |
| 0.210 inche | es |
| Terminal L | ength: |
| 0.500 inche | 9S |
| Overall Dia | ameter: |
| 0.230 inche | es |
| Internal Co | onfiguration: |
| Junction co | ontact |
| Joint Elect | tronic Device Engineering Council/jedec/case Outline Designation: |
| To-18 | |
| Electrode | Internally-electrically Connected To Case: |
| Collector | |
| Mounting | Method: |
| Terminal | |
| Terminal C | Circle Diameter: |
| 0.100 inche | 25 |
| Features P | Provided: |
| Hermeticall | ly sealed case |
| Semicond | uctor Material: |
| Silicon | |
| Voltage Ra | ating In Volts Per Characteristic: |
| 60.0 repeti | itive peak off-state voltage |
| Current Ra | ating Per Characteristic: |
| 200.00 milli | iamperes forward current, total rms nanoamperes |
| Maximum | Operating Tempurature Per Measurement Point: |
| 159.0 degre | ees celsius ambient air |
| Special Fe | atures: |
| Junction pa | attern arrangement: pnpnp |
| Terminal T | ype And Quantity: |
| 3 uninsulate | ed wire lead |
| Shelf Life: | |
| N/a | |
| Unit Of Me | asure: |
| | |
| Demilitariz | zation: |
| No | |
| Fiig: | |
| A110a0 | |